

1. Record Nr.	UNINA9911099739303321
Autore	Thompson James <1973->
Titolo	British political culture and the idea of 'public opinion', 1867-1914 / / James Thompson
Pubbl/distr/stampa	Cambridge : , : Cambridge University Press, , 2013
ISBN	1-107-27250-5 1-139-88935-4 1-107-27189-4 1-107-27847-3 1-107-27398-6 1-107-27522-9 1-139-20861-6
Descrizione fisica	1 online resource (viii, 293 pages) : digital, PDF file(s)
Classificazione	HIS015000
Disciplina	306.20941/09034
Soggetti	Political culture - Great Britain - History Public opinion - Great Britain - History Press - Great Britain - History Great Britain Politics and government
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Title from publisher's bibliographic system (viewed on 05 Oct 2015).
Nota di bibliografia	Includes bibliographical references and index.
Nota di contenuto	Acknowledgements -- Introduction: rethinking public opinion in late nineteenth-century Britain -- 1. An open demos? The public and the question of membership -- 2. The ghost in the machine: locating public opinion -- 3. The mind of the nation? Reason and the public -- 4. Political economy and the idea of 'public opinion' -- 5. Representing labour: the labour movement, politics and the public -- 6. Conclusion: 'public opinion' and political culture in Britain, 1870-1914.
Sommario/riassunto	Newspapers, periodicals, pamphlets and books all reflect the ubiquity of 'public opinion' in political discourse in late nineteenth and early twentieth-century Britain. Through close attention to debates across the political spectrum, James Thompson charts the ways in which Britons sought to locate 'public opinion' in an era prior to polling. He shows that 'public opinion' was the principal term through which the

link between the social and the political was interrogated, charted and contested and charts how the widespread conviction that the public was growing in power raised significant issues about the kind of polity emerging in Britain. He also examines how the early Labour party negotiated the language of 'public opinion' and sought to articulate Labour interests in relation to those of the public. In so doing he sheds important new light on the character of Britain's liberal political culture and on Labour's place in and relationship to that culture.

2. Record Nr.	UNINA9911087362903321
Autore	Webster D. G. <1975->
Titolo	Adaptive governance : the dynamics of Atlantic fisheries management / D.G. Webster
Pubbl/distr/stampa	Cambridge, Mass., : MIT Press, c2009
ISBN	0-262-28587-8 1-4356-8174-6
Edizione	[1st ed.]
Descrizione fisica	1 online resource (415 p.)
Collana	Global environmental accord
Disciplina	338.3/727
Soggetti	Fishery management Fishery policy Intergovernmental cooperation
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Bibliographic Level Mode of Issuance: Monograph
Nota di bibliografia	Includes bibliographical references (p. [373]-380) and index.
Nota di contenuto	Intro -- Contents -- Series Foreword -- Foreword -- Preface -- Acknowledgments -- 1 - Adaptive Governance -- 2 - The Vulnerability Response Framework -- I - Tropical Tunas -- 3 - Bigeye Tuna -- 4 - Yellowfin Tuna -- 5 - Skipjack Tuna -- II - Billfishes -- 6 - Northern Swordfish -- 7 - Southern Swordfish -- 8 - Blue Marlin and White Marlin -- III - Bluefin Tuna -- 9 - Western Bluefin Tuna -- 10 - Eastern Bluefin Tuna -- 11 - Conclusion -- Appendix A - Group of 18 -- Appendix B - Comprehensive Vulnerability Classifications -- Appendix C - Summary of Evidence from the Cases -- Appendix D - Proxy Indicators for Competitiveness -- Appendix E - Proxy Indicators for Flexibility -- Appendix F - Delineating High-Flex and Low-Flex Phases

Sommario/riassunto This title develops and applies an innovative theoretical framework that links domestic economic vulnerabilities to national policy positions and international management in the context of Atlantic fisheries.

3. **Record Nr.** UNINA9911091026703321

Titolo III-nitride : semiconductor materials / / editor, Zhe Chuan Feng

Pubbl/distr/stampa London, : Imperial College Press, c2006

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Edizione [1st ed.]

Descrizione fisica 1 online resource (440 p.)

Altri autori (Persone) FengZhe Chuan

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Soggetti Semiconductors - Materials
Nitrides

Lingua di pubblicazione Inglese

Formato Materiale a stampa

Livello bibliografico Monografia

Note generali Description based upon print version of record.

Nota di bibliografia Includes bibliographical references.

Nota di contenuto CONTENTS ; Preface ; Chapter 1 Hydride vapor phase epitaxy of group III nitride materials
; 1.Introduction ; 2.Experiment ; 3.Material Properties ; 3.1. Undoped GaN layers
; 3.2. Si-doped GaN layers ; 3.3. Mg-doped GaN layers
; 3.4. Zn-doped GaN layers
; 3.5. AlN layers
3.6. AlGaIn layers 3.7. InN and InGaIn layers
; 4.New directions in HVPE development ;
4.1. Large area and multi wafer HVPE growth

- ; 4.2. Multi-layer structures
- ; 4.3. P-n junctions
- ; 4.4. Structures with two dimensional carrier gas
- ; 4.5. Nano structures and porous materials
- 5.Applications of HVPE grown group III nitride materials
- 5.1. Substrate applications
 - ; 5.1.1. Template substrates
 - ; 5.1.2. Free-standing substrates
 - ; 5.1.3. Bulk substrates
- ; 5.2. Device Applications
- ; 6.Conclusions
- Chapter 2 Planar MOVPE technology for epitaxy of III-nitride materials
- 1. History of Reactor Development for III-Nitrides
- ; 2. Types of Planar Reactors
- ; 3. Reactor Modeling
- ; 3.1. Growth Kinetics of Group-III Nitride MOVPE
- ; 3.2. Modeling of MOVPE processes
- 3.3. Horizontal Tube Reactors: Flow Dynamics and Reactor Technology
- 3.4. Planetary Reactors: Transport Phenomena & Parameter Dependencies
- ; 4. In-situ Technology in Nitride MOCVD Systems
- ; 5. The Mass Production of GaN and Related Materials
- ; 5.1. Optoelectronic Device Structures
- 5.2. Growth in the 8x4 inch Configuration

Sommario/riassunto

III-Nitride semiconductor materials - (Al, In, Ga)N - are excellent wide band gap semiconductors very suitable for modern electronic and optoelectronic applications. Remarkable breakthroughs have been achieved recently, and current knowledge and data published have to be modified and upgraded. This book presents the new developments and achievements in the field. Written by renowned experts, the review chapters in this book cover the most important topics and achievements in recent years, discuss progress made by different groups, and suggest future directions. Each chapter also describes th
